HIGH POWER OPERATIONAL AMPLIFIER 151/152

M.S.KENNEDY CORP.

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FEATURES:

- Internally Compensated For Gains > 10 V/V
- Improved Replacement for OMA541SKB
- Low Cost
- High Voltage Operation: 150V
- Low Quiescent Current: 30mA Typ.
- · High Output Current: 5A Min.
- No Second Breakdown
- High Speed: 27V/µS Typ.
- Monolithic MOS Technology





MIL-PRF-38534 QUALIFIED

(315) 701-6751

DESCRIPTION:

The MSK 151 is a high power monolithic MOSFET operational amplifier ideally suited for high power amplification and magnetic deflection applications. With a total supply voltage rating of 150 volts and 5A of available output current, the MSK 151 is also an excellent low cost choice for motor drive circuits. The MOSFET output frees the MSK 151 from secondary breakdown limitations and power dissipation is kept to a minimum with a quiescent current rating of only 30mA. The MSK 151 is packaged in a hermetically sealed 8 pin power dip and is internally compensated for gains larger than 10 V/V. For applications requiring heat sinking, the MSK 152 is available with bolt down tabs and is otherwise identical to the MSK 151 (see mechanical specifications).

EQUIVALENT SCHEMATIC



TYPICAL APPLICATIONS

- PA Audio
- Magnetic Deflection
- Motor Drive
- Noise Cancellation

- -Vcc 1
- N/C 2
- **Output Drive** 3
- Current Sense 4

8 Inverting Input

- 7 Non-Inverting Input
- 6 N/C
- 5 +Vcc

ABSOLUTE MAXIMUM RATINGS

Vcc ②	Total Supply Voltage	150V
± Іоит	Output Current (within S.O.A.)	$\pm 5A$
VIND	Input Voltage (Differential)	±16V
Vin	Input Voltage (Common Mode)	±Vcc
Тı	Junction Temperature	50°C

Тsт	Storage Temperature65°C to +150°C
TLD	Lead Temperature
Tc	Case Operating Temperature
	(MSK151B/152B)55°C to +125°C
	(MSK151/152)40°C to +85°C
R th	Thermal Resistance (DC)
	Junction to Case

ELECTRICAL SPECIFICATIONS

Parameter	Test Conditions $\ensuremath{}$	Group A	MSK151B/152B		52B	MSK151/152			
Falameter		Subgroup	Min.	Тур.	Max.	Min.	Тур.	Max.	Units
STATIC									
Supply Voltage Range		-	±15	±50	±75	±15	±50	±75	V
		1	-	± 30	±50	-	± 30	±50	mA
Quiescent Current 2 4	VIN = OV	2	-	±20	±45	-	-	-	mA
			-	±35	±65	-	-	-	mA
Offset Voltage	VIN=OV	1	-	± 5	±10	-	± 5	±15	mV
Offset Voltage Drift ④	VIN=OV	2,3	-	±10	±50	-	±10	-	µV/°C
Offset Voltage vs \pm Vcc ④	VIN=OV	1	-	±8	±15	-	±8	±15	μ V/V
Input Bias Current		1,3	-	±20	±100	-	±20	±100	pА
	VCM = OV		-	-	± 50	-	-	-	nA
Input Impedance ④	(DC)	-	-	10 ¹¹	-	-	10 11	-	Ω
Input Capacitance ④		-	-	5	-	-	5	-	pF
Common Mode Rejection \oplus	$V_{CM} = \pm 30 VDC$	-	90	106	-	90	106	-	dB
Noise	10KHz BW	-	-	10	-	-	10	-	μVrms
OUTPUT									
Output Voltage Swing	$IOUT = \pm 5A Peak$	4	±40	±42	-	±40	±42	-	V
Output Current	Vout = MAX	4	±5	± 5.5	-	±5	± 5.5	-	А
Power Bandwidth ④	Vout = 80Vpp	-	-	66	-	-	66	-	KHz
Settling Time to 0.1% ③④	10V Step	-	-	2	-	-	2	-	μS
Capacitive Load ④	Av = +10 V/V	-	10	-	-	10	-	-	nF
TRANSFER CHARACTERISTICS									
Slew Rate		4	20	27	-	20	27	-	V/µS
Open Loop Voltage Gain ④ F=15Hz		4	94	106	-	94	106	-	dB

NOTES:

- (1) Unless otherwise noted $\pm Vcc = \pm 50VDC$. (2) Derate maximum supply voltage $0.5V/^{\circ}C$ below $Tc = +25^{\circ}C$. No derating is needed above $Tc = 25^{\circ}C$. (3) Av = -10V/V measured in false summing junction circuit. (4) Devices shall be capable of meeting the parameter, but need not be tested. Typical parameters are for reference only.
- ⑤ Industrial grade devices shall be tested to subgroups 1 and 4 unless otherwise requested.

Military grade devices shall be tested to subgroups 1 and 4 alloss otherwise requires Military grade devices ('B' suffix) shall be 100% tested to subgroups 1,2,3 and 4.
Subgroup 5 and 6 testing available upon request.

(8) Subgroup 1,4 Tc = +25 °CSubgroup 2,5 Tc = +125 °CSubgroup 3,6 Ta = -55 °C

APPLICATION NOTES

CURRENT LIMIT (SEE TYPICAL CONNECTION DIAGRAM)

A value of current limit resistance can be calculated as follows:

Where:

RCL is the current limit resistor value

ICL is the current limit

0.05 * ICL is the voltage dropped in the current limit path across internal impedances other than the actual current limit resistor

0.83 volts is the voltage drop that must be developed across the current limit connections to activate the current limit circuit

The maximum practical value of current limit resistance is 16 ohms. The current limit resistor will decrease available output voltage swing in the following manner:

$$V_R = IO * R_{CL}$$

VR is the reduction in output voltage swing due to the current limit resistor. It is recommended the user limit output current to a value as close to the required output current as possible, without clipping output voltage swing. Current limit will vary with case temperature. Refer to the typical performance curves to predict current limit drift. If current limit is not required replace the resistor with a short.

STABILITY

It is recommended that the parallel sum of the input and feedback resistor be 1000 ohms or less to minimize phase shift caused by the R-C network formed by the input resistor, feedback resistor and input capacitance. An effective method of checking amplifier stability is to apply the worst case capacitive load to the output of the amplifier and drive a small signal square wave across it. If overshoot is less than 25%, the system will typically be stable.

INPUT PROTECTION

Input protection circuitry within the MSK 151/152 will clip differential input voltages greater than 16 volts. The inputs are also protected against common mode voltages up to the supply rails as well as static discharge. There are 300 ohm current limiting resistors in series with each input. These resistors may become damaged in the event the input overload is capable of driving currents above 1mA. If severe overload conditions are expected, external input current limiting resistors are recommended.

SAFE OPERATING AREA (SOA)

The MOSFET output stage of this power operational amplifier has two distinct limitations:

1. The current handling capability of the die metallization.

2. The junction temperature of the output MOSFET's.

NOTE: The output stage is protected against transient flyback. However, for protection against sustained, high energy flyback, external fast-recovery reverse biased diodes should be connected from the output to ground.







TYPICAL CONNECTION DIAGRAM

TYPICAL PERFORMANCE CURVES





ESD TRIANGLE INDICATES PIN 1. ALL DIMENSIONS ARE ± 0.010 INCHES UNLESS OTHERWISE LABELED.

ORDERING INFORMATION

Part Number	Screening Level
MSK151	Industrial
MSK151B	Military-Mil-PRF-38534
MSK152	Industrial
MSK152B	Military-Mil-PRF-38534

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